

IRF7503TRPBF

Data Sheet

30V Dual N-Channel HEXFET Power MOSFET in a Micro 8 package; Similar to the IRF7503TR with lead-free packaging.

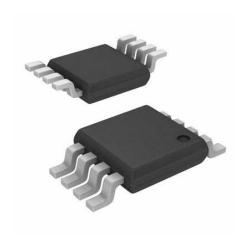
Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case MSOP8

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for IRF7503TRPBF or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFQ

General Description

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Fifth Generation HEXFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, combined with the fast switching speed and ruggedized device design that HEXFET Power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in a wide variety of applications. The new Micro8 package, with half the footprint area of the standard SO-8, provides the smallest footprint available in an SOIC outline. This makes the Micro8 an ideal device for applications where printed circuit board space is at a

premium. The low profile (<1.1mm) of the Micro8 will allow it to fit easily into extremely thin application environments such as portable electronics and PCMCIA cards.

Generation V Technology Ultra Low On-Resistance Dual N-Channel MOSFET Very Small SOIC Package Low Profile (<1.1mm) Available in Tape & Reel Fast Switching

Features

RoHS Compliant

Fast Switching

Low Profile (less than 1.1mm)

Dual N-Channel MOSFET

Related Products



IRLTS6342TRPBF

Infineon Technologies Corporation TSOP-6



IRF9310PBF

Infineon Technologies Corporation SOIC-8



IRF9358TRPBF

Infineon Technologies Corporation SOP-8



IRFB3307ZPBF

Infineon Technologies Corporation TO-220AB



IRLHS6376TRPBF

Infineon Technologies Corporation PQFN2x2DD



IRFH9310TRPBF

Infineon Technologies Corporation PQFN-8



IRFB7430PBF

Infineon Technologies Corporation TO-220



IRF7351TRPBF

Infineon Technologies Corporation SOIC-8